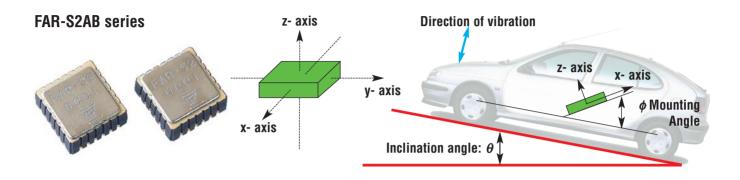
THE POSSIBILITIES ARE INFINITE



ACCELEROMETER FACTSHEET

MEMS 3-AXIS ACCELEROMETER

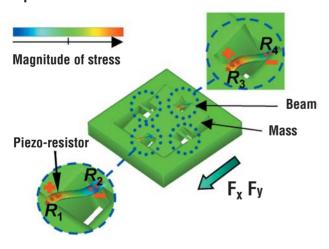


Fujitsu successfully developed the 'FAR-S2AB' series, 3-axis Accelerometer, using state-of-the-art MEMS technology. This small and highly sensitive accelerometer can detect acceleration, inclination and

vibration by measuring the motion in the x-, y-, and z-axis simultaneously.

By sensing the mounting angle, the sensor can assist in compensating for the devices mounting angle, and therefore makes it possible to use normal SMD technology in highdensity boards, and also to realise the precise detection of the inclination angle. An interface IC within the sensor package also has temperature sensing and self-diagnosis functions.

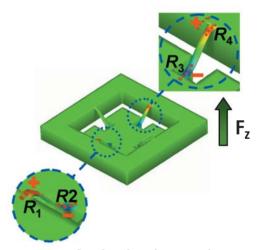
Principle of detection



Acceleration along x- (y-) axis

The MEMS 3-axis accelerometer consists of a Mass at the centre of the sensor's chip, which is suspended by 4 Beams doped with Piezoresistive material.

When the sensor is subjected to acceleration in any direction, the movement of the Mass causes the 4 Beams to deform and so change the resistance in the piezo material.



Acceleration along z- axis

This enables the sensor to detect the acceleration motion.



ACCELEROMETER FACTSHEET

Features

- 3-axis single-chip accelerometer
- Built-in IC integrating temperature sensor and self-diagnosis function
- High sensitivity: up to 1,000 mV/G
- External connection for low pass filters
- Automatic correction of mounting angle
- Small size: 5.0 x 5.0 x 2.3mm
- Lead-free

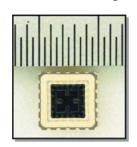
Applications

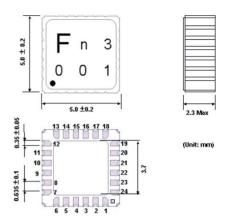
- Navigation system
- Automotive stability system
- Roll-over system
- Stability control of industrial machinery
- Industrial and home appliances
- Humanoid robots

Ideal solution for automotive stability system

- Fujitsu MEMS 3-axis accelerometer: FAR-S2AB
- Fujitsu gyro sensor: FAR-S1BG
- Fujitsu automotive MCU: MB90F351
- Connected to the stability control main ECU via CAN

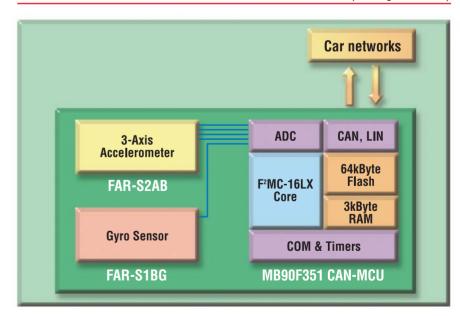
Small size & high sensitivity FAR-S2AB series





Specification

•	
Detection method	Piezo-resistive
Operation temperature range	-40 to +85°C
Supply voltage	3 to 5.5V
Current consumption	3mA
Sensitivity	~1,000mV/G
OG offset voltage	2.5V ± 5%
Shock resistance	< 5,000G
Dimensions	5.0 x 5.0 x 2.3mm (Packaged with IC)



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